NSN 5961-01-193-5722

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View Online at https://aerobasegroup.com/nsn/5961-01-193-5722 **Inclosure Material:** Metal **Overall Length:** 1.252 inches **Overall Height:** 0.340 inches **Overall Width:** 0.700 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Unthreaded hole **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: -200.0 collector to emitter voltage, dc and -200.0 collector to base voltage, dc and -5.0 emitter to base voltage, dc **Current Rating Per Characteristic:** 10.00 amperes source cutoff current and 2.00 amperes source cutoff current **Power Rating Per Characteristic:** 44.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: pnp **Precious Material And Location:** Terminal surface option gold **Precious Material:** Gold **Test Data Document:** 83843-934a297 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 2 pin and 1 case

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N/a

Shelf Life:

Unit Of Measure:

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Demilitarization:

No

Fiig:

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